Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-511-0019

Inclosure N	laterial:
Metal	
Overall Ler	ngth:
1.453 inche	S
Function F	or Which Designed:
Rectifier	
Mounting F	Facility Quantity:
1	
Mounting M	lethod:
Threaded st	tud
Overall Wid	dth Across Flats:
Between 0.6	677 inches and 0.690 inches
Thready Qt	y Per Inch (tpi):
28	
Thread Size	e:
0.250 inche	s
Semicondu	ictor Material:
Silicon	
Voltage Ra	ting In Volts Per Characteristic:
400.0 repet	titive peak reverse voltage
Current Ra	ting Per Characteristic:
40.00 ampe	res forward current, average absolute
Special Fea	atures:
Fast recove	ry; junction temperature range minus 46.0 to plus 125.0 degrees c
Thread Ser	ies Designator:
Unf	
Terminal T	ype And Quantity:
1 tab, solde	er lug and 1 threaded stud
Shelf Life:	
N/a	
Unit Of Mea	asure:
Demilitariza	ation:
No	
Fiig:	
A110a0	